

ES3AF THRU ES3JF

Surface Mount Superfast Recovery Rectifier

FEATURES:

- For surface mounted applications
- Low profile package
- Glass Passivated Chip Junction
- Superfast reverse recovery time
- Lead free in comply with EU RoHS 2011/65/EU directives

Circuit Diagram & Pin Configuration:





SMAF

Absolute Maximum Ratings and Characteristics

Ratings at 25 °C ambient temperature unless otherwise specified. Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Parameter	Symbols	ES3AF	ES3BF	ES3CF	ES3DF	ES3EF	ES3GF	ES3JF	Units
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	150	200	300	400	600	V
Maximum RMS voltage	V _{RMS}	35	70	105	140	210	280	420	V
Maximum DC Blocking Voltage	V _{DC}	50	100	150	200	300	400	600	V
Maximum Average Forward Rectified Current at T_c = 125 °C	I _{F(AV)}	3						А	
Peak Forward Surge Current 8.3 ms Single Half Sine Wave Superimposed on Rated Load	I _{FSM}	80						А	
Maximum Forward Voltage at 3 A	V _F	1 1.25 1.6				1.68	V		
Maximum DC Reverse Current $T_a = 25 ^{\circ}\text{C}$ at Rated DC Blocking Voltage $T_a = 125 ^{\circ}\text{C}$	I _R	5 100						μА	
Typical Junction Capacitance at V _R =4V, f=1MHz	C _j	40					pF		
Maximum Reverse Recovery Time (1)	t _{rr}	35					ns		
Typical Thermal Resistance (2)	$R_{ heta_{JA}}$ $R_{ heta_{JC}}$	50 16					°C/W		
Operating and Storage Temperature Range	T_{j}, T_{stg}	-55 ~ +150						°C	

^(1) Measured with I_{F} = 0.5 A, I_{R} = 1 A, I_{rr} = 0.25 A.

Marking

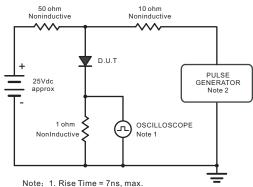
Type number	Marking code				
ES3AF	ES3A				
ES3BF	ES3B				
ES3CF	ES3C				
ES3DF	ES3D				
ES3EF	ES3E				
ES3GF	ES3G				
ES3JF	ES3J				

^(2) P.C.B. mounted with 2.0" X 2.0" (5 X 5 cm) copper pad areas.



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Fig.1 Reverse Recovery Time Characteristic And Test Circuit Diagram



- Input Impedance = 1megohm,22pF.
 - 2. Ries Time =10ns, max. Source Impedance = 50 ohms.

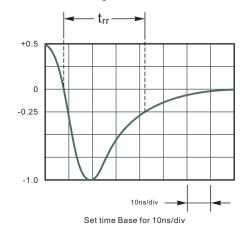


Fig.2 Maximum Average Forward Current Rating

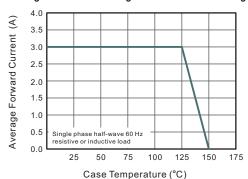


Fig.3 Typical Reverse Characteristics

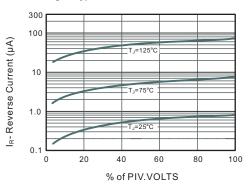


Fig.4 Typical Forward Characteristics

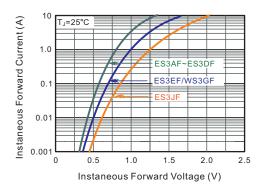


Fig.5 Typical Junction Capacitance

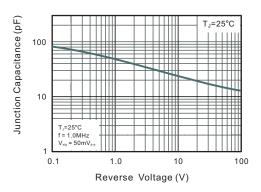
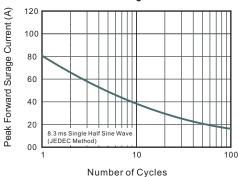


Fig.6 Maximum Non-Repetitive Peak Forward Surage Current



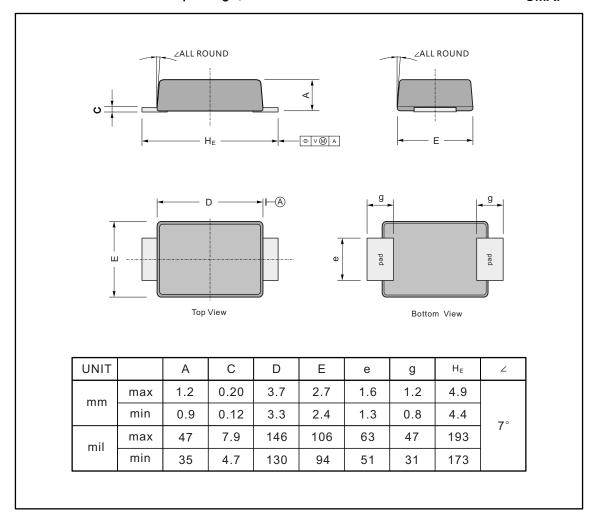




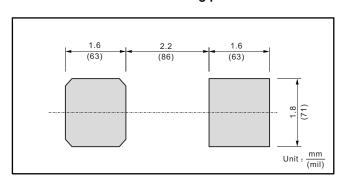
PACKAGE OUTLINE

Plastic surface mounted package; 2 leads

SMAF



The recommended mounting pad size





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